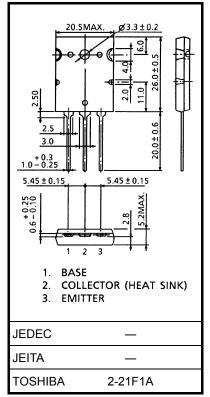
TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington Power Transistor)

# 2SD1314

High Power Switching Applications Motor Control Applications

- High DC current gain:  $h_{FE} = 100 \text{ (min)} (V_{CE} = 5 \text{ V}, I_{C} = 15 \text{ A})$
- Low saturation voltage:  $V_{CE}$  (sat) = 2 V (max) (I<sub>C</sub> = 15 A, I<sub>B</sub> = 0.4 A)
- High speed:  $t_f = 3 \mu s (max) (I_C = 15 A)$

#### Absolute Maximum Ratings (Tc = 25°C) Characteristics Symbol Rating Unit V 600 Collector-base voltage VCBO 450 V Collector-emitter voltage VCEO Emitter-base voltage 6 V $V_{EBO}$ DC IC 15 Collector current Α Pulse 30 ICP Base current 1.0 А $I_B$ 150 w Collector power dissipation $\mathsf{P}_\mathsf{C}$ 150 °C Junction temperature Тj °C -55 to 150



Weight: 9.75 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

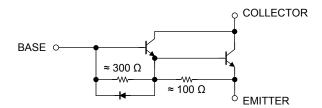
Tstq

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Equivalent Circuit**

Storage temperature range

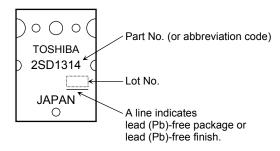


Unit: mm

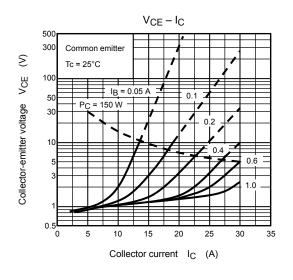
Electrical Characteristics (Tc = 25°C)

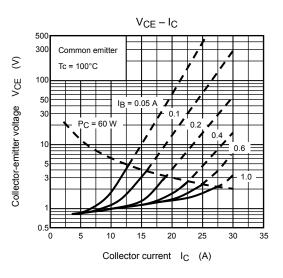
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 600 V, I <sub>E</sub> = 0	_	_	1.0	mA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	_	_	200	mA
Collector-emitter sustaining voltage		V <sub>CEO (SUS)</sub>	I <sub>C</sub> = 0.5 A, L = 40 mH	450	_	_	V
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 15 A	100	_	_	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	- I <sub>C</sub> = 15 A, I <sub>B</sub> = 0.4 A	_	_	2.0	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>		_	_	2.5	V
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0, f = 1 MHz	_	150	_	pF
Switching time	Turn-on time	t <sub>on</sub>	$50 \ \mu s$ $Input$ $Input$ $IB1$ $G$	_	_	1.0	μs
	Storage time	t <sub>stg</sub>		_	_	12	
	Fall time	t <sub>f</sub>		_	_	3.0	

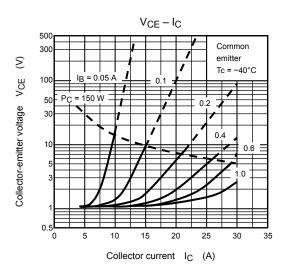
### Marking

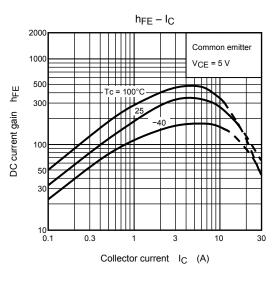


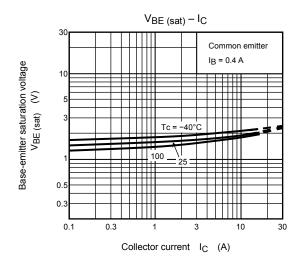
## **TOSHIBA**



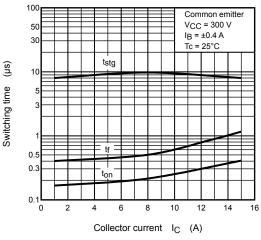


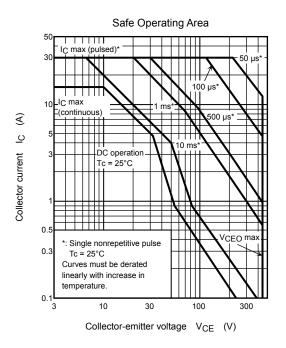






Switching time – IC





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